

# 50 μA, 550 kHz Rail-to-Rail Op Amp

#### **Features**

• Gain Bandwidth Product: 550 kHz (typ.)

• Supply Current: I<sub>O</sub> = 50 μA (typ.)

• Supply Voltage: 1.8V to 5.5V

• Rail-to-Rail Input/Output

• Extended Temperature Range: -40°C to +125°C

• Available in 5-pin SC-70 and SOT-23 packages

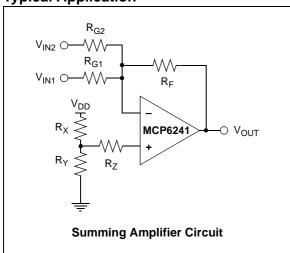
### **Applications**

- Automotive
- · Portable Equipment
- Photodiode (Transimpedance) Amplifier
- Analog Filters
- · Notebooks and PDAs
- · Battery-Powered Systems

#### **Available Tools**

- SPICE Macro Models (at www.microchip.com)
- FilterLab<sup>®</sup> Software (at www.microchip.com)

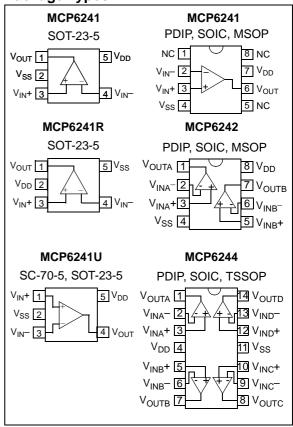
### **Typical Application**



# **Description**

The Microchip Technology Inc. MCP6241/2/4 operational amplifiers (op amps) provide wide bandwidth for the quiescent current. The MCP6241/2/4 has a 550 kHz Gain Bandwidth Product (GBWP) and 68° (typ.) phase margin. This family operates from a single supply voltage as low as 1.8V, while drawing 50  $\mu\text{A}$  (typ.) quiescent current. In addition, the MCP6241/2/4 family supports rail-to-rail input and output swing, with a common mode input voltage range of  $V_{DD}$  + 300 mV to  $V_{SS}$  – 300 mV. These op amps are designed in one of Microchip's advanced CMOS processes.

# **Package Types**



# 1.0 ELECTRICAL CHARACTERISTICS

# **Absolute Maximum Ratings †**

All Inputs and Outputs $V_{SS} - 0.3V$ to $V_{DD} + 0.3V$
All inputs and outputs
Difference Input Voltage V <sub>DD</sub> – V <sub>SS</sub>
Output Short Circuit Currentcontinuous
Current at Input Pins±2 mA
Current at Output and Supply Pins±30 mA
Storage Temperature65°C to +150°C
Maximum Junction Temperature (T <sub>J</sub> )+150°C
ESD Protection On All Pins (HBM;MM)≥ 4 kV; 300V

† Notice: Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at those or any other conditions above those indicated in the operational listings of this specification is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability.

# DC ELECTRICAL CHARACTERISTICS

<b>Electrical Characteristics</b> : Unless $V_{CM} = V_{DD}/2$ , $R_L = 100 \text{ k}\Omega$ to $V_{DD}/2$	s otherwise 2 and V <sub>OUT</sub>	indicated, · ≈ V <sub>DD</sub> /2.	$T_A = +25^{\circ}$	C, V <sub>DD</sub> = +1	.8V to -	+5.5V, V <sub>SS</sub> = GND,
Parameters	Sym	Min	Тур	Max	Units	Conditions
Input Offset						
Input Offset Voltage	Vos	-5.0	_	+5.0	mV	$V_{CM} = V_{SS}$
Extended Temperature	V <sub>OS</sub>	-7.0	_	+7.0	mV	T <sub>A</sub> = -40°C to +125°C, V <sub>CM</sub> = V <sub>SS</sub> ( <b>Note</b> )
Input Offset Drift with Temperature	$\Delta V_{OS}/\Delta T_{A}$	_	±3.0	_	μV/°C	$T_A$ = -40°C to +125°C, $V_{CM} = V_{SS}$
Power Supply Rejection	PSRR	_	83	_	dB	$V_{CM} = V_{SS}$
Input Bias Current and Impedan	се					
Input Bias Current:	Ι <sub>Β</sub>	_	±1.0	_	pА	
At Temperature	I <sub>B</sub>	_	20	_	pА	$T_A = +85$ °C
At Temperature	I <sub>B</sub>	_	1100	_	pА	T <sub>A</sub> = +125°C
Input Offset Current	Ios	_	±1.0	_	pА	
Common Mode Input Impedance	Z <sub>CM</sub>	_	10 <sup>13</sup>   6	_	$\Omega  pF$	
Differential Input Impedance	Z <sub>DIFF</sub>	_	10 <sup>13</sup>   3	_	$\Omega  pF$	
Common Mode						
Common Mode Input Range	$V_{CMR}$	$V_{SS} - 0.3$	—	$V_{DD} + 0.3$	<b>V</b>	
Common Mode Rejection Ratio	CMRR	60	75		dB	$V_{CM} = -0.3V$ to 5.3V, $V_{DD} = 5V$
Open-Loop Gain						
DC Open-Loop Gain (large signal)	A <sub>OL</sub>	90	110		dB	$V_{OUT} = 0.3V$ to $V_{DD} - 0.3V$ , $V_{CM} = V_{SS}$
Output						
Maximum Output Voltage Swing	$V_{OL}, V_{OH}$	V <sub>SS</sub> + 35	_	V <sub>DD</sub> – 35	mV	$R_L = 10 \text{ k}\Omega$ , 0.5V Output Overdrive
Output Short-Circuit Current	I <sub>SC</sub>	_	±6	_	mA	V <sub>DD</sub> = 1.8V
	I <sub>SC</sub>	_	±23	_	mA	V <sub>DD</sub> = 5.5V
Power Supply						
Supply Voltage	$V_{DD}$	1.8	_	5.5	V	
Quiescent Current per Amplifier	ΙQ	30	50	70	μΑ	$I_{O} = 0, V_{CM} = V_{DD} - 0.5V$

**Note:** The SC-70 package is only tested at +25°C.

# **AC ELECTRICAL CHARACTERISTICS**

**Electrical Characteristics:** Unless otherwise indicated,  $T_A$  = +25°C,  $V_{DD}$  = +1.8 to 5.5V,  $V_{SS}$  = GND,  $V_{CM}$  =  $V_{DD}/2$ ,  $V_{OUT} \approx V_{DD}/2$ ,  $R_L$  = 10 kΩ to  $V_{DD}/2$  and  $C_L$  = 60 pF.

OOT DD 7 E DD E T									
Parameters	Sym	Sym Min Typ Max		Units	Conditions				
AC Response									
Gain Bandwidth Product	GBWP	_	550	_	kHz				
Phase Margin	PM	_	68	_	٥	G = +1			
Slew Rate	SR	_	0.30	_	V/µs				
Noise	<u>.</u>								
Input Noise Voltage	E <sub>ni</sub>	_	10	_	μV <sub>P-P</sub>	f = 0.1 Hz to 10 Hz			
Input Noise Voltage Density	e <sub>ni</sub>	_	45	_	nV/√Hz	f = 1 kHz			
Input Noise Current Density	i <sub>ni</sub>	_	0.6	_	fA/√Hz	f = 1 kHz			

# **TEMPERATURE CHARACTERISTICS**

Electrical Characteristics: Unless other	<b>Electrical Characteristics:</b> Unless otherwise indicated, $V_{DD} = +1.8V$ to +5.5V and $V_{SS} = GND$ .									
Parameters	Sym	Min	Тур	Max	Units	Conditions				
Temperature Ranges										
Extended Temperature Range	T <sub>A</sub>	-40	_	+125	°C					
Operating Temperature Range	T <sub>A</sub>	-40	_	+125	°C	(Note)				
Storage Temperature Range	T <sub>A</sub>	-65	_	+150	°C					
Thermal Package Resistances										
Thermal Resistance, 5L-SC70	$\theta_{JA}$	_	331	_	°C/W					
Thermal Resistance, 5L-SOT-23	$\theta_{JA}$	_	256	_	°C/W					
Thermal Resistance, 8L-MSOP	$\theta_{JA}$	_	206	_	°C/W					
Thermal Resistance, 8L-PDIP	$\theta_{JA}$	_	85	_	°C/W					
Thermal Resistance, 8L-SOIC	$\theta_{JA}$	_	163	_	°C/W					
Thermal Resistance, 14L-PDIP	$\theta_{JA}$	_	70	_	°C/W					
Thermal Resistance, 14L-SOIC	$\theta_{JA}$	_	120	_	°C/W					
Thermal Resistance, 14L-TSSOP	$\theta_{JA}$	_	100	_	°C/W					

**Note:** The internal Junction Temperature (T<sub>J</sub>) must not exceed the Absolute Maximum specification of +150°C.

# 2.0 TYPICAL PERFORMANCE CURVES

**Note:** The graphs and tables provided following this note are a statistical summary based on a limited number of samples and are provided for informational purposes only. The performance characteristics listed herein are not tested or guaranteed. In some graphs or tables, the data presented may be outside the specified operating range (e.g., outside specified power supply range) and therefore outside the warranted range.

**Note:** Unless otherwise indicated,  $T_A$  = +25°C,  $V_{DD}$  = +1.8V to +5.5V,  $V_{SS}$  = GND,  $V_{CM}$  =  $V_{DD}/2$ ,  $V_{OUT} \approx V_{DD}/2$ ,  $R_L$  = 100 k $\Omega$  to  $V_{DD}/2$  and  $C_L$  = 60 pF.

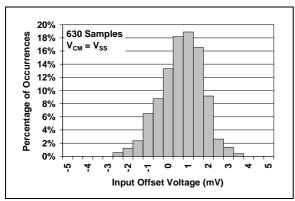
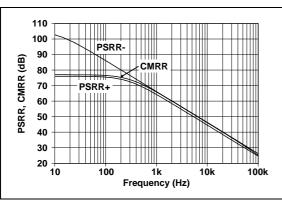


FIGURE 2-1: Input Offset Voltage.



**FIGURE 2-2:** PSRR, CMRR vs. Frequency.

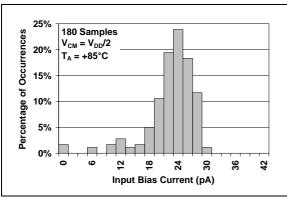
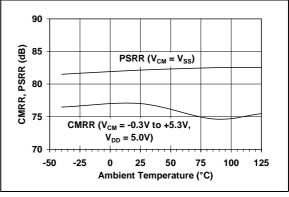


FIGURE 2-3: Input Bias Current at +85°C.



**FIGURE 2-4:** CMRR, PSRR vs. Ambient Temperature.

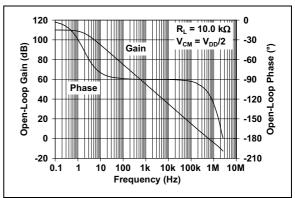


FIGURE 2-5: Open-Loop Gain, Phase vs. Frequency.

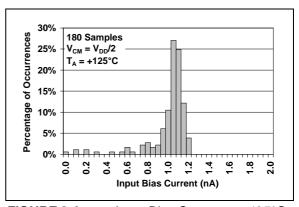
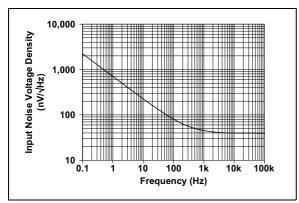
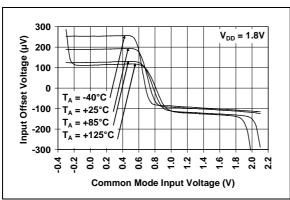


FIGURE 2-6: Input Bias Current at +125°C.

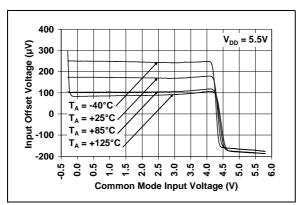
**Note:** Unless otherwise indicated,  $T_A$  = +25°C,  $V_{DD}$  = +1.8V to +5.5V,  $V_{SS}$  = GND,  $V_{CM}$  =  $V_{DD}/2$ ,  $V_{OUT} \approx V_{DD}/2$ ,  $R_L$  = 100 k $\Omega$  to  $V_{DD}/2$  and  $C_L$  = 60 pF.



**FIGURE 2-7:** Input Noise Voltage Density vs. Frequency.



**FIGURE 2-8:** Input Offset Voltage vs. Common Mode Input Voltage at  $V_{DD} = 1.8V$ .



**FIGURE 2-9:** Input Offset Voltage vs. Common Mode Input Voltage at  $V_{DD} = 5.5V$ .

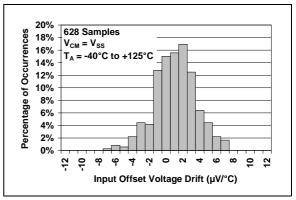
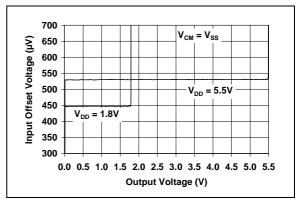
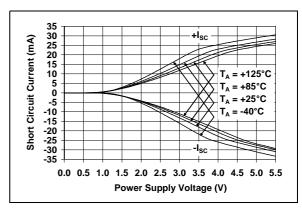


FIGURE 2-10: Input Offset Voltage Drift.

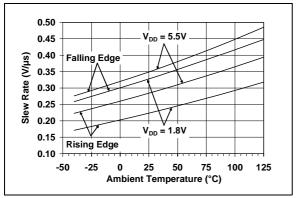


**FIGURE 2-11:** Input Offset Voltage vs. Output Voltage.

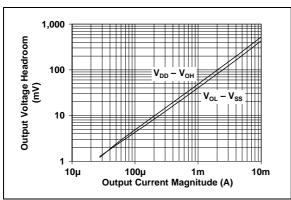


**FIGURE 2-12:** Output Short-Circuit Current vs. Ambient Temperature.

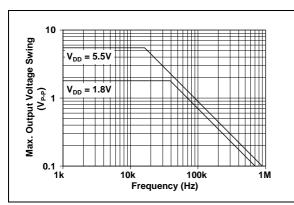
**Note:** Unless otherwise indicated,  $T_A$  = +25°C,  $V_{DD}$  = +1.8V to +5.5V,  $V_{SS}$  = GND,  $V_{CM}$  =  $V_{DD}/2$ ,  $V_{OUT} \approx V_{DD}/2$ ,  $R_L$  = 100 k $\Omega$  to  $V_{DD}/2$  and  $C_L$  = 60 pF.



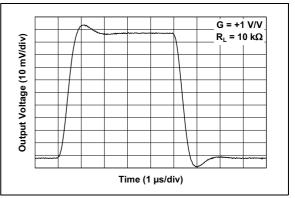
**FIGURE 2-13:** Slew Rate vs. Ambient Temperature.



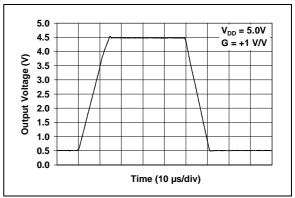
**FIGURE 2-14:** Output Voltage Headroom vs. Output Current Magnitude.



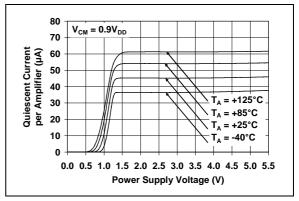
**FIGURE 2-15:** Maximum Output Voltage Swing vs. Frequency.



**FIGURE 2-16:** Small-Signal, Non-Inverting Pulse Response.



**FIGURE 2-17:** Large-Signal, Non-Inverting Pulse Response.



**FIGURE 2-18:** Quiescent Current vs. Power Supply Voltage.

#### 3.0 PIN DESCRIPTIONS

Descriptions of the pins are listed in Table 3-1 (single op amps) and Table 3-2 (dual and quad op amps).

TABLE 3-1: PIN FUNCTION TABLE FOR SINGLE OP AMPS

MCP6241 (PDIP, SOIC, MSOP)	MCP6241 (SOT-23-5)	MCP6241R (SOT-23-5)	MCP6241U (SOT-23-5)	Symbol	Description
6	1	1	4	V <sub>OUT</sub>	Analog Output
2	4	4	3	V <sub>IN</sub> -	Inverting Input
3	3	3	1	V <sub>IN</sub> +	Non-inverting Input
7	5	2	5	$V_{DD}$	Positive Power Supply
4	2	5	2	$V_{SS}$	Negative Power Supply
1, 5, 8	_	_	_	NC	No Internal Connection

TABLE 3-2: PIN FUNCTION TABLE FOR DUAL AND QUAD OP AMPS

MCP6242	MCP6244	Symbol	Description
1	1	V <sub>OUTA</sub>	Analog Output (op amp A)
2	2	V <sub>INA</sub> -	Inverting Input (op amp A)
3	3	V <sub>INA</sub> +	Non-inverting Input (op amp A)
8	4	$V_{DD}$	Positive Power Supply
5	5	V <sub>INB</sub> +	Non-inverting Input (op amp B)
6	6	V <sub>INB</sub> -	Inverting Input (op amp B)
7	7	V <sub>OUTB</sub>	Analog Output (op amp B)
_	8	V <sub>OUTC</sub>	Analog Output (op amp C)
_	9	V <sub>INC</sub> -	Inverting Input (op amp C)
_	10	V <sub>INC</sub> +	Non-inverting Input (op amp C)
4	11	V <sub>SS</sub>	Negative Power Supply
_	12	V <sub>IND</sub> +	Non-inverting Input (op amp D)
_	13	V <sub>IND</sub> -	Inverting Input (op amp D)
_	14	V <sub>OUTD</sub>	Analog Output (op amp D)

# 3.1 Analog Outputs

The output pins are low-impedance voltage sources.

# 3.2 Analog Inputs

The non-inverting and inverting inputs are high-impedance CMOS inputs with low bias currents.

# 3.3 Power Supply (V<sub>SS</sub> and V<sub>DD</sub>)

The positive power supply ( $V_{DD}$ ) is 1.8V to 5.5V higher than the negative power supply ( $V_{SS}$ ). For normal operation, the other pins are between  $V_{SS}$  and  $V_{DD}$ .

Typically, these parts are used in a single-(positive) supply configuration. In this case,  $V_{SS}$  is connected to ground and  $V_{DD}$  is connected to the supply.  $V_{DD}$  will need a local bypass capacitor (typically 0.01  $\mu F$  to 0.1  $\mu F$ ) within 2 mm of the  $V_{DD}$  pin. These parts can share a bulk capacitor (typically 1  $\mu F$  to 100  $\mu F$ ) with other nearby analog parts; it needs to be within 100 mm of the  $V_{DD}$  pin.

#### 4.0 APPLICATION INFORMATION

The MCP6241/2/4 family of op amps is manufactured using Microchip's state-of-the-art CMOS process and is specifically designed for low-power and general-purpose applications. The low supply voltage, low quiescent current and wide bandwidth makes the MCP6241/2/4 ideal for battery-powered applications.

# 4.1 Rail-to-Rail Inputs

The MCP6241/2/4 op amps are designed to prevent phase reversal when the input pins exceed the supply voltages. Figure 4-1 shows the input voltage exceeding the supply voltage without any phase reversal.

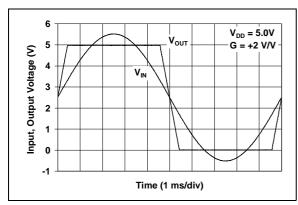
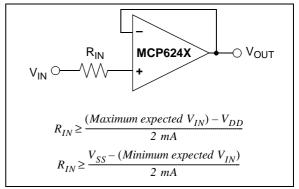


FIGURE 4-1: The MCP6241/2/4 Show No Phase Reversal.

The input stage of the MCP6241/2/4 op amps use two differential input stages in parallel. One operates at low common mode input voltage (V<sub>CM</sub>) and the other at high V<sub>CM</sub>. With this topology, the device operates with V<sub>CM</sub> up to 300 mV above V<sub>DD</sub> and 300 mV below V<sub>SS</sub>. The Input Offset Voltage is measured at V<sub>CM</sub> = V<sub>SS</sub> – 300 mV and V<sub>DD</sub> + 300 mV to ensure proper operation.

Input voltages that exceed the input voltage range ( $V_{SS}-0.3V$  to  $V_{DD}+0.3V$  at 25°C) can cause excessive current to flow into or out of the input pins. Current beyond  $\pm 2$  mA can cause reliability problems. Applications that exceed this rating must be externally limited with a resistor, as shown in Figure 4-2.



**FIGURE 4-2:** Input Current-Limiting Resistor (R<sub>IN</sub>).

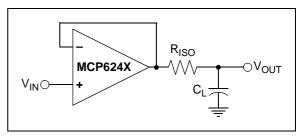
# 4.2 Rail-to-Rail Output

The output voltage range of the MCP6241/2/4 op amps is  $V_{DD}-35$  mV (max.) and  $V_{SS}+35$  mV (min.) when  $R_L=10$  k $\Omega$  is connected to  $V_{DD}/2$  and  $V_{DD}=5.5$ V. Refer to Figure 2-14 for more information.

## 4.3 Capacitive Loads

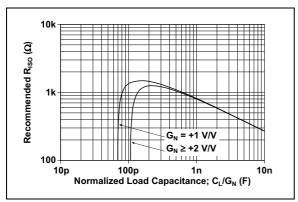
Driving large capacitive loads can cause stability problems for voltage-feedback op amps. As the load capacitance increases, the feedback loop's phase margin decreases and the closed-loop bandwidth is reduced. This produces gain peaking in the frequency response, with overshoot and ringing in the step response. A unity-gain buffer (G = +1) is the most sensitive to capacitive loads, but all gains show the same general behavior.

When driving large capacitive loads with these op amps (e.g.,  $> 70 \, \text{pF}$  when G = +1), a small series resistor at the output (R<sub>ISO</sub> in Figure 4-3) improves the feedback loop's phase margin (stability) by making the output load resistive at higher frequencies. The bandwidth will be generally lower than the bandwidth with no capacitive load.



**FIGURE 4-3:** Output resistor,  $R_{ISO}$  stabilizes large capacitive loads.

Figure 4-4 gives recommended  $R_{ISO}$  values for different capacitive loads and gains. The x-axis is the normalized load capacitance  $(C_L/G_N)$ , where  $G_N$  is the circuit's noise gain. For non-inverting gains,  $G_N$  and the signal gain are equal. For inverting gains,  $G_N$  is 1 + |Signal Gain| (e.g., -1 V/V gives  $G_N = +2$  V/V).



**FIGURE 4-4:** Recommended R<sub>ISO</sub> Values for Capacitive Loads.

After selecting  $R_{\rm ISO}$  for your circuit, double-check the resulting frequency response peaking and step response overshoot. Evaluation on the bench and simulations with the MCP6241/2/4 SPICE macro model are very helpful. Modify  $R_{\rm ISO}$ 's value until the response is reasonable.

### 4.4 Supply Bypass

With this op amp, the power supply pin ( $V_{DD}$  for single-supply) should have a local bypass capacitor (i.e., 0.01  $\mu F$  to 0.1  $\mu F$ ) within 2 mm for good high-frequency performance. It can use a bulk capacitor (i.e., 1  $\mu F$  or larger) within 100 mm to provide large, slow currents. This bulk capacitor can be shared with other nearby analog parts.

### 4.5 Unused Op Amps

An unused op amp in a quad package (MCP6244) should be configured as shown in Figure 4-5. Both circuits prevent the output from toggling and causing crosstalk. Circuit A can use any reference voltage between the supplies, provides a buffered DC voltage, and minimizes the supply current draw of the unused op amp. Circuit B minimizes the number of components, but may draw a little more supply current for the unused op amp.

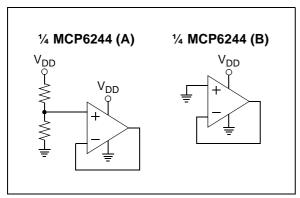
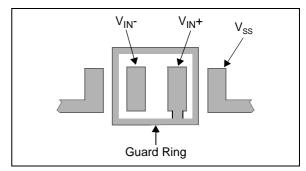


FIGURE 4-5: Unused Op Amps.

### 4.6 PCB Surface Leakage

In applications where low input bias current is critical, PCB (printed circuit board) surface leakage effects need to be considered. Surface leakage is caused by humidity, dust or other contamination on the board. Under low humidity conditions, a typical resistance between nearby traces is  $10^{12}\Omega$ . A 5V difference would cause 5 pA of current to flow, which is greater than the MCP6241/2/4 family's bias current at 25°C (1 pA, typ.).

The easiest way to reduce surface leakage is to use a guard ring around sensitive pins (or traces). The guard ring is biased at the same voltage as the sensitive pin. An example of this type of layout is shown in Figure 4-6.



**FIGURE 4-6:** Example Guard Ring Layout for Inverting Gain.

- 1. Non-inverting Gain and Unity-Gain Buffer:
  - a. Connect the non-inverting pin  $(V_{\text{IN}}+)$  to the input with a wire that does not touch the PCB surface.
  - b. Connect the guard ring to the inverting input pin (V<sub>IN</sub>–). This biases the guard ring to the common mode input voltage.
- Inverting Gain and Transimpedance Amplifiers (convert current to voltage, such as photo detectors):
  - a. Connect the guard ring to the non-inverting input pin ( $V_{IN}$ +). This biases the guard ring to the same reference voltage as the op amp (e.g.,  $V_{DD}/2$  or ground).
  - b. Connect the inverting pin (V<sub>IN</sub>-) to the input with a wire that does not touch the PCB surface.

# 4.7 Application Circuits

# 4.7.1 MATCHING THE IMPEDANCE AT THE INPUTS

To minimize the effect of offset voltage in an amplifier circuit, the impedances at the inverting and non-inverting inputs need to be matched. This is done by choosing the circuit resistor values so that the total resistance at each input is the same. Figure 4-7 shows a summing amplifier circuit.

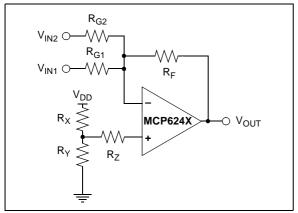


FIGURE 4-7: Summing Amplifier Circuit.

To match the inputs, set all voltage sources to ground and calculate the total resistance at the input nodes. In this summing amplifier circuit, the resistance at the inverting input is calculated by setting  $V_{IN1}$ ,  $V_{IN2}$  and  $V_{OUT}$  to ground. In this case,  $R_{G1}$ ,  $R_{G2}$  and  $R_F$  are in parallel. The total resistance at the inverting input is:

$$R_{VIN} - = \frac{1}{\left(\frac{1}{R_{GI}} + \frac{1}{R_{G2}} + \frac{1}{R_{F}}\right)}$$

Where:

R<sub>VIN</sub><sup>-</sup> = total resistance at the inverting input

At the non-inverting input,  $V_{DD}$  is the only voltage source. When  $V_{DD}$  is set to ground, both  $R_X$  and  $R_Y$  are in parallel. The total resistance at the non-inverting input is:

$$R_{VIN^{+}} = \frac{1}{\left(\frac{1}{R_{V}} + \frac{1}{R_{V}}\right)} + R_{Z}$$

Where:

R<sub>VIN</sub>+ = total resistance at the inverting input

To minimize offset voltage and increase circuit accuracy, the resistor values need to meet the condition:

$$R_{VIN^+} = R_{VIN} -$$

# 4.7.2 COMPENSATING FOR THE PARASITIC CAPACITANCE

In analog circuit design, the PCB parasitic capacitance can compromise the circuit behavior; Figure 4-8 shows a typical scenario. If the input of an amplifier sees parasitic capacitance of several picofarad ( $C_{PARA}$ , which includes the common mode capacitance of 6 pF, typical) and large  $R_F$  and  $R_G$ , the frequency response of the circuit will include a zero. This parasitic zero introduces gain peaking and can cause circuit instability.

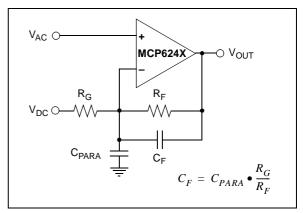


FIGURE 4-8: Effect of Parasitic Capacitance at the Input.

One solution is to use smaller resistor values to push the zero to a higher frequency. Another solution is to compensate by introducing a pole at the point at which the zero occurs. This can be done by adding  $C_F$  in parallel with the feedback resistor  $(R_F)$ .  $C_F$  needs to be selected so that the ratio  $C_{PARA}$ : $C_F$  is equal to the ratio of  $R_F$ : $R_G$ .

# 5.0 DESIGN TOOLS

Microchip provides the basic design tools needed for the MCP6241/2/4 family of op amps.

#### 5.1 SPICE Macro Model

The latest SPICE macro model for the MCP6241/2/4 op amps is available on our web site at www.microchip.com. This model is intended to be an initial design tool that works well in the op amp's linear region of operation at room temperature. See the macro model file for information on its capabilities.

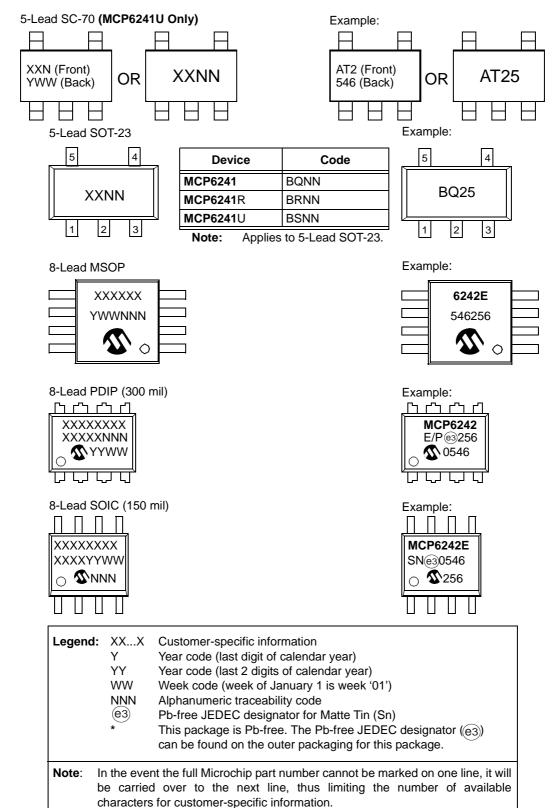
Bench testing is a very important part of any design and cannot be replaced with simulations. Also, simulation results using this macro model need to be validated by comparing them to the data sheet specifications and characteristic curves.

# 5.2 FilterLab<sup>®</sup> Software

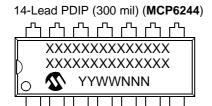
Microchip's FilterLab software is an innovative tool that simplifies analog active-filter (using op amps) design. Available at no cost from our web site at www.microchip.com, the FilterLab design tool provides full schematic diagrams of the filter circuit with component values. It also outputs the filter circuit in SPICE format, which can be used with the macro model to simulate actual filter performance.

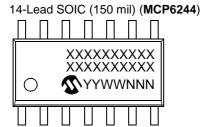
#### 6.0 PACKAGING INFORMATION

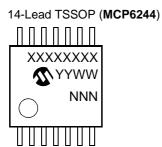
# 6.1 Package Marking Information

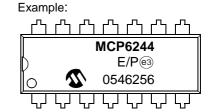


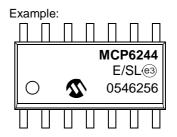
# **Package Marking Information (Continued)**

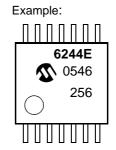




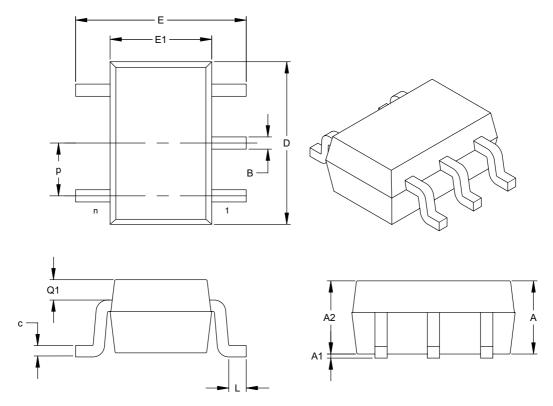








# 5-Lead Plastic Small Outline Transistor Package (LT) (SC-70)



	Units		INCHES			MILLIMETERS*		
Dimension	Limits	MIN	NOM	MAX	MIN	NOM	MAX	
Number of Pins	n		5			5		
Pitch	р		.026 (BSC)			0.65 (BSC)		
Overall Height	Α	.031		.043	0.80		1.10	
Molded Package Thickness	A2	.031		.039	0.80		1.00	
Standoff	A1	.000		.004	0.00		0.10	
Overall Width	Е	.071		.094	1.80		2.40	
Molded Package Width	E1	.045		.053	1.15		1.35	
Overall Length	D	.071		.087	1.80		2.20	
Foot Length	L	.004		.012	0.10		0.30	
Top of Molded Pkg to Lead Shoulder	Q1	.004		.016	0.10		0.40	
Lead Thickness	С	.004		.007	0.10		0.18	
Lead Width	В	.006		.012	0.15		0.30	

<sup>\*</sup>Controlling Parameter

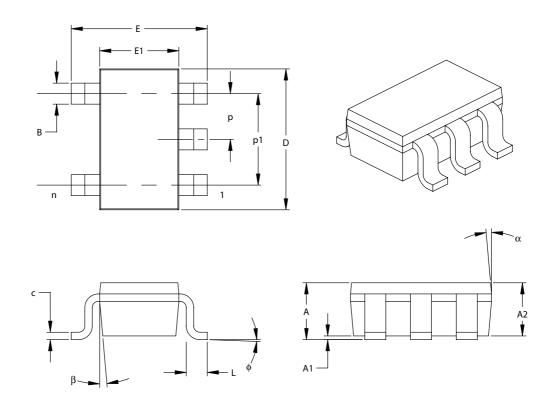
Notes:

Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .005" (0.127mm) per side.

JEITA (EIAJ) Standard: SC-70

Drawing No. C04-061

# 5-Lead Plastic Small Outline Transistor (OT) (SOT23)



	Units	Units INCHES*			N	MILLIMETERS		
Dimension L	imits.	MIN	NOM	MAX	MIN	NOM	MAX	
Number of Pins	n		5			5		
Pitch	р		.038			0.95		
Outside lead pitch (basic)	p1		.075			1.90		
Overall Height	Α	.035	.046	.057	0.90	1.18	1.45	
Molded Package Thickness	A2	.035	.043	.051	0.90	1.10	1.30	
Standoff	A1	.000	.003	.006	0.00	0.08	0.15	
Overall Width	E	.102	.110	.118	2.60	2.80	3.00	
Molded Package Width	E1	.059	.064	.069	1.50	1.63	1.75	
Overall Length	D	.110	.116	.122	2.80	2.95	3.10	
Foot Length	L	.014	.018	.022	0.35	0.45	0.55	
Foot Angle	ф	0	5	10	0	5	10	
Lead Thickness	С	.004	.006	.008	0.09	0.15	0.20	
Lead Width	В	.014	.017	.020	0.35	0.43	0.50	
Mold Draft Angle Top	α	0	5	10	0	5	10	
Mold Draft Angle Bottom	β	0	5	10	0	5	10	

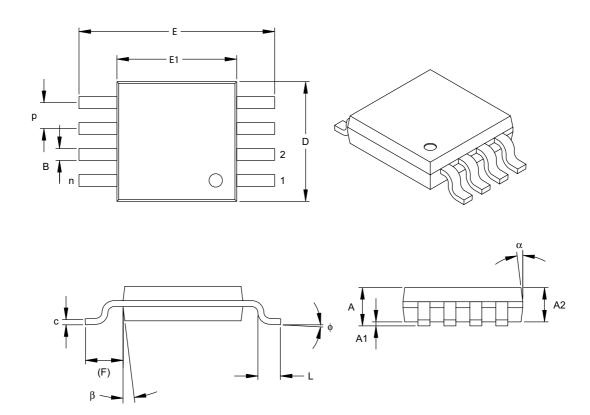
<sup>\*</sup>Controlling Parameter

Notes:

Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .005" (0.127mm) per side.

EIAJ Equivalent: SC-74A Drawing No. C04-091

# 8-Lead Plastic Micro Small Outline Package (MS) (MSOP)



	Units		INCHES			MILLIMETERS*		
Dimension Lin	nits	MIN	NOM	MAX	MIN	NOM	MAX	
Number of Pins	n		8			8		
Pitch	р		.026 BSC			0.65 BSC		
Overall Height	Α	-	-	.043	-	-	1.10	
Molded Package Thickness	A2	.030	.033	.037	0.75	0.85	0.95	
Standoff	A1	.000	-	.006	0.00	-	0.15	
Overall Width	E		.193 TYP.			4.90 BSC		
Molded Package Width	E1		.118 BSC			3.00 BSC		
Overall Length	D		.118 BSC			3.00 BSC		
Foot Length	L	.016	.024	.031	0.40	0.60	0.80	
Footprint (Reference)	F		.037 REF			0.95 REF		
Foot Angle	ф	0°	-	8°	0°	-	8°	
Lead Thickness	С	.003	.006	.009	0.08	-	0.23	
Lead Width	В	.009	.012	.016	0.22	-	0.40	
Mold Draft Angle Top	α	5°	-	15°	5°	-	15°	
Mold Draft Angle Bottom	β	5°	-	15°	5°	-	15°	

<sup>\*</sup>Controlling Parameter

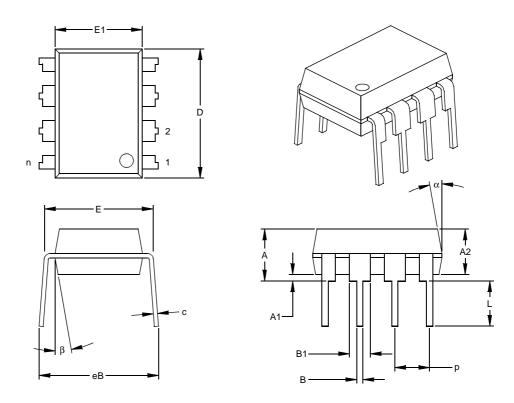
Notes:

Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .010" (0.254mm) per side.

JEDEC Equivalent: MO-187

Drawing No. C04-111

# 8-Lead Plastic Dual In-line (P) - 300 mil (PDIP)



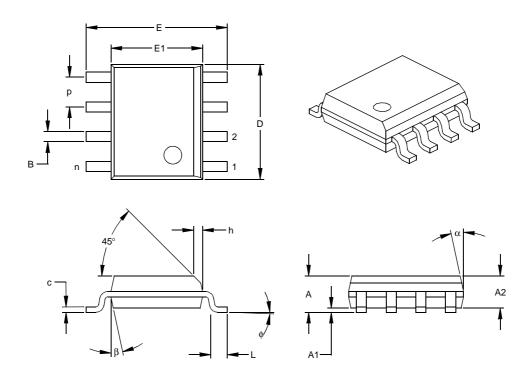
	Units	Units INCHES*			N	11LLIMETERS	3
Dimens	ion Limits	MIN	NOM	MAX	MIN	NOM	MAX
Number of Pins	n		8			8	
Pitch	р		.100			2.54	
Top to Seating Plane	Α	.140	.155	.170	3.56	3.94	4.32
Molded Package Thickness	A2	.115	.130	.145	2.92	3.30	3.68
Base to Seating Plane	A1	.015			0.38		
Shoulder to Shoulder Width	Е	.300	.313	.325	7.62	7.94	8.26
Molded Package Width	E1	.240	.250	.260	6.10	6.35	6.60
Overall Length	D	.360	.373	.385	9.14	9.46	9.78
Tip to Seating Plane	L	.125	.130	.135	3.18	3.30	3.43
Lead Thickness	С	.008	.012	.015	0.20	0.29	0.38
Upper Lead Width	B1	.045	.058	.070	1.14	1.46	1.78
Lower Lead Width	В	.014	.018	.022	0.36	0.46	0.56
Overall Row Spacing	§ eB	.310	.370	.430	7.87	9.40	10.92
Mold Draft Angle Top	α	5	10	15	5	10	15
Mold Draft Angle Bottom	β	5	10	15	5	10	15

Notes:
Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .010" (0.254mm) per side.

JEDEC Equivalent: MS-001
Drawing No. C04-018

<sup>\*</sup> Controlling Parameter § Significant Characteristic

# 8-Lead Plastic Small Outline (SN) - Narrow, 150 mil (SOIC)



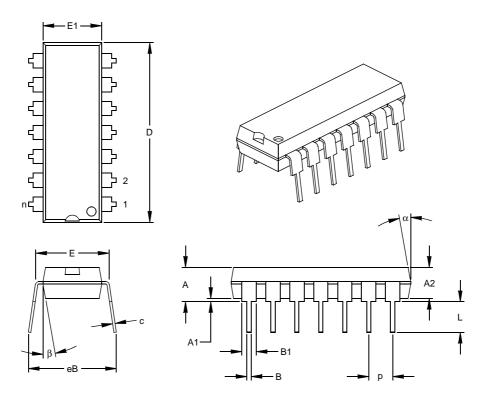
	Units	INCHES*			MILLIMETERS		
Dimension	Limits	MIN	NOM	MAX	MIN	NOM	MAX
Number of Pins	n		8			8	
Pitch	р		.050			1.27	
Overall Height	Α	.053	.061	.069	1.35	1.55	1.75
Molded Package Thickness	A2	.052	.056	.061	1.32	1.42	1.55
Standoff §	A1	.004	.007	.010	0.10	0.18	0.25
Overall Width	Е	.228	.237	.244	5.79	6.02	6.20
Molded Package Width	E1	.146	.154	.157	3.71	3.91	3.99
Overall Length	D	.189	.193	.197	4.80	4.90	5.00
Chamfer Distance	h	.010	.015	.020	0.25	0.38	0.51
Foot Length	L	.019	.025	.030	0.48	0.62	0.76
Foot Angle	ф	0	4	8	0	4	8
Lead Thickness	С	.008	.009	.010	0.20	0.23	0.25
Lead Width	В	.013	.017	.020	0.33	0.42	0.51
Mold Draft Angle Top	α	0	12	15	0	12	15
Mold Draft Angle Bottom	β	0	12	15	0	12	15

Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed

.010" (0.254mm) per side. JEDEC Equivalent: MS-012 Drawing No. C04-057

<sup>\*</sup> Controlling Parameter § Significant Characteristic

# 14-Lead Plastic Dual In-line (P) - 300 mil (PDIP)

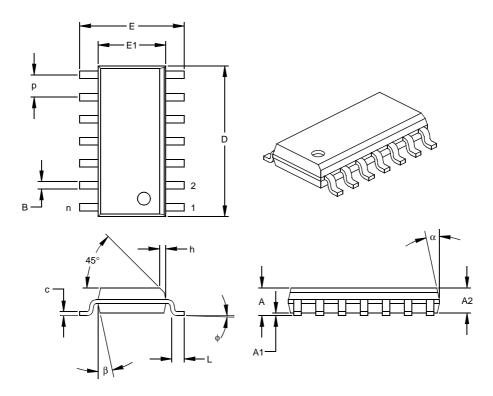


	Units		INCHES*		N	MILLIMETERS		
Dimensi	on Limits	MIN	NOM	MAX	MIN	NOM	MAX	
Number of Pins	n		14			14		
Pitch	р		.100			2.54		
Top to Seating Plane	Α	.140	.155	.170	3.56	3.94	4.32	
Molded Package Thickness	A2	.115	.130	.145	2.92	3.30	3.68	
Base to Seating Plane	A1	.015			0.38			
Shoulder to Shoulder Width	Е	.300	.313	.325	7.62	7.94	8.26	
Molded Package Width	E1	.240	.250	.260	6.10	6.35	6.60	
Overall Length	D	.740	.750	.760	18.80	19.05	19.30	
Tip to Seating Plane	L	.125	.130	.135	3.18	3.30	3.43	
Lead Thickness	С	.008	.012	.015	0.20	0.29	0.38	
Upper Lead Width	B1	.045	.058	.070	1.14	1.46	1.78	
Lower Lead Width	В	.014	.018	.022	0.36	0.46	0.56	
Overall Row Spacing	§ eB	.310	.370	.430	7.87	9.40	10.92	
Mold Draft Angle Top	α	5	10	15	5	10	15	
Mold Draft Angle Bottom	β	5	10	15	5	10	15	

Notes:
Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .010" (0.254mm) per side.
JEDEC Equivalent: MS-001
Drawing No. C04-005

<sup>\*</sup> Controlling Parameter § Significant Characteristic

# 14-Lead Plastic Small Outline (SL) - Narrow, 150 mil (SOIC)



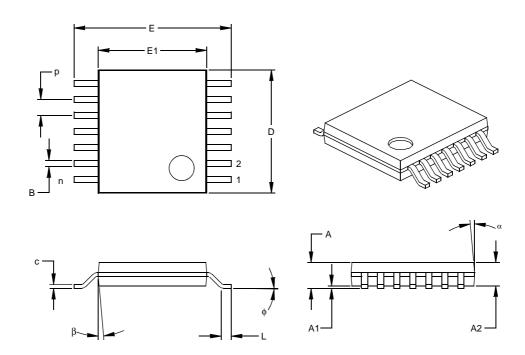
	Units	its INCHES*			MILLIMETERS			
Dimension	n Limits	MIN	NOM	MAX	MIN	NOM	MAX	
Number of Pins	n		14			14		
Pitch	р		.050			1.27		
Overall Height	Α	.053	.061	.069	1.35	1.55	1.75	
Molded Package Thickness	A2	.052	.056	.061	1.32	1.42	1.55	
Standoff §	A1	.004	.007	.010	0.10	0.18	0.25	
Overall Width	Е	.228	.236	.244	5.79	5.99	6.20	
Molded Package Width	E1	.150	.154	.157	3.81	3.90	3.99	
Overall Length	D	.337	.342	.347	8.56	8.69	8.81	
Chamfer Distance	h	.010	.015	.020	0.25	0.38	0.51	
Foot Length	L	.016	.033	.050	0.41	0.84	1.27	
Foot Angle	ф	0	4	8	0	4	8	
Lead Thickness	С	.008	.009	.010	0.20	0.23	0.25	
Lead Width	В	.014	.017	.020	0.36	0.42	0.51	
Mold Draft Angle Top	α	0	12	15	0	12	15	
Mold Draft Angle Bottom	β	0	12	15	0	12	15	

Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed

.010" (0.254mm) per side. JEDEC Equivalent: MS-012 Drawing No. C04-065

<sup>\*</sup> Controlling Parameter § Significant Characteristic

# 14-Lead Plastic Thin Shrink Small Outline (ST) – 4.4 mm (TSSOP)



	Units	INCHES			MILLIMETERS*		
Dimension	Limits	MIN	MOM	MAX	MIN	MOM	MAX
Number of Pins	n		14			14	
Pitch	р		.026			0.65	
Overall Height	Α			.043			1.10
Molded Package Thickness	A2	.033	.035	.037	0.85	0.90	0.95
Standoff §	A1	.002	.004	.006	0.05	0.10	0.15
Overall Width	Е	.246	.251	.256	6.25	6.38	6.50
Molded Package Width	E1	.169	.173	.177	4.30	4.40	4.50
Molded Package Length	D	.193	.197	.201	4.90	5.00	5.10
Foot Length	L	.020	.024	.028	0.50	0.60	0.70
Foot Angle	ф	0	4	8	0	4	8
Lead Thickness	С	.004	.006	.008	0.09	0.15	0.20
Lead Width	B1	.007	.010	.012	0.19	0.25	0.30
Mold Draft Angle Top	α	0	5	10	0	5	10
Mold Draft Angle Bottom	β	0	5	10	0	5	10

Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed

.005" (0.127mm) per side. JEDEC Equivalent: MO-153 Drawing No. C04-087

<sup>\*</sup> Controlling Parameter § Significant Characteristic

NOTES:

# APPENDIX A: REVISION HISTORY

# Revision C (March 2005)

The following is the list of modifications:

- 1. Added the MCP6244 quad op amp.
- 2. Re-compensated parts. Specifications that change are: Gain Bandwidth Product (BWP) and Phase Margin (PM) in AC Electrical Characteristics table.
- 3. Corrected plots in Section 2.0 "Typical Performance Curves".
- 4. Added Section 3.0 "Pin Descriptions".
- 5. Added new SC-70 package markings. Added PDIP-14, SOIC-14, and TSSOP-14 packages and corrected package marking information (Section 6.0 "Packaging Information").
- 6. Added Appendix A: "Revision History".

# **Revision B (August 2004)**

# Revision A (March 2004)

• Original Release of this Document.

NOTES:

# PRODUCT IDENTIFICATION SYSTEM

To order or obtain information, e.g., on pricing or delivery, refer to the factory or the listed sales office.

PART NO.	<u>X</u>	<u>-x</u> /xx		Examples:			
		 nperature Range	 Package	a)	MCP6241-E/SN:	Extended Temp., 8LD SOIC package.	
Alternate Pinout				b)	MCP6241-E/MS:	Extended Temp., 8LD MSOP package.	
Device:	MCP6241T: Single Op Amp (	mp (MSOP, PDIP, SOIC) mp (Tape and Reel)	c)	MCP6241-E/P:	Extended Temp., 8LD PDIP package.		
	MCP6241RT: MCP6241UT:	(MSOP, SOIC, SOT-23) Single Op Amp (Tape and Reel) (SOT-23) Single Op Amp (Tape and Reel)	d)	MCP6241RT-E/OT:	Tape and Reel, Extended Temp., 5LD SOT-23 package		
	MCP6242: MCP6242T:	(SC-70, SOT Dual Op Am	r-23) p p (Tape and Reel)	e)	MCP6241UT-E/OT:	Tape and Reel, Extended Temp., 5LD SOT-23 package.	
	MCP6244: MCP6244T:	Quad Op Am	np np (Tape and Reel)	f)	MCP6241UT-E/LT:	Tape and Reel, Extended Temp., 5LD SC-70 package.	
Temperature Range: E = -40°C to +125°C			a)	MCP6242-E/SN:	Extended Temp., 8LD SOIC package.		
Package:	LT = Plastic Package (SC-70), 5-lead (MCP6241U MS = Plastic Micro Small Outline (MSOP), 8-lead		b)	MCP6242-E/MS:	Extended Temp., 8LD MSOP package.		
	OT = Plastic S	DIP (300 mil Body), 8-lead, 14-lead Small Outline Transistor (SOT-23), 5-lead 3241, MCP6241R, MCP6241U)	c)	MCP6242-E/P:	Extended Temp., 8LD PDIP package.		
	SN = Plastic S SL = Plastic S	SOIC (150 mil Body), 8-lead SOIC (150 mil Body), 14-lead FSSOP (4.4 mil Body), 14-lead		d)	MCP6242T-E/SN:	Tape and Reel, Extended Temp., 8LD SOIC package.	
				a)	MCP6244-E/P:	Extended Temp., 14LD PDIP package.	
				b)	MCP6244-E/SL:	Extended Temp., 14LD SOIC package.	
				c)	MCP6244-E/ST:	Extended Temp., 14LD TSSOP package.	
				d)	MCP6244T-E/SL:	Tape and Reel, Extended Temp., 14LD SOIC package.	
				e)	MCP6244T-E/ST:	Tape and Reel, Extended Temp., 14LD TSSOP package.	

NOTES:

#### Note the following details of the code protection feature on Microchip devices:

- Microchip products meet the specification contained in their particular Microchip Data Sheet.
- Microchip believes that its family of products is one of the most secure families of its kind on the market today, when used in the intended manner and under normal conditions.
- There are dishonest and possibly illegal methods used to breach the code protection feature. All of these methods, to our
  knowledge, require using the Microchip products in a manner outside the operating specifications contained in Microchip's Data
  Sheets. Most likely, the person doing so is engaged in theft of intellectual property.
- Microchip is willing to work with the customer who is concerned about the integrity of their code.
- Neither Microchip nor any other semiconductor manufacturer can guarantee the security of their code. Code protection does not
  mean that we are guaranteeing the product as "unbreakable."

Code protection is constantly evolving. We at Microchip are committed to continuously improving the code protection features of our products. Attempts to break Microchip's code protection feature may be a violation of the Digital Millennium Copyright Act. If such acts allow unauthorized access to your software or other copyrighted work, you may have a right to sue for relief under that Act.

Information contained in this publication regarding device applications and the like is provided only for your convenience and may be superseded by updates. It is your responsibility to ensure that your application meets with your specifications. MICROCHIP MAKES NO REPRESENTATIONS OR WAR-RANTIES OF ANY KIND WHETHER EXPRESS OR IMPLIED, WRITTEN OR ORAL, STATUTORY OR OTHERWISE, RELATED TO THE INFORMATION, INCLUDING BUT NOT LIMITED TO ITS CONDITION, QUALITY, PERFORMANCE, MERCHANTABILITY OR FITNESS FOR PURPOSE. Microchip disclaims all liability arising from this information and its use. Use of Microchip's products as critical components in life support systems is not authorized except with express written approval by Microchip. No licenses are conveyed, implicitly or otherwise, under any Microchip intellectual property rights.

#### **Trademarks**

The Microchip name and logo, the Microchip logo, Accuron, dsPIC, KEELOQ, microID, MPLAB, PIC, PICmicro, PICSTART, PRO MATE, PowerSmart, rfPIC, and SmartShunt are registered trademarks of Microchip Technology Incorporated in the U.S.A. and other countries.

AmpLab, FilterLab, Migratable Memory, MXDEV, MXLAB, PICMASTER, SEEVAL, SmartSensor and The Embedded Control Solutions Company are registered trademarks of Microchip Technology Incorporated in the U.S.A.

Analog-for-the-Digital Age, Application Maestro, dsPICDEM, dsPICDEM.net, dsPICworks, ECAN, ECONOMONITOR, FanSense, FlexROM, fuzzyLAB, In-Circuit Serial Programming, ICSP, ICEPIC, MPASM, MPLIB, MPLINK, MPSIM, PICkit, PICDEM, PICDEM.net, PICLAB, PICtail, PowerCal, PowerInfo, PowerMate, PowerTool, rfLAB, rfPICDEM, Select Mode, Smart Serial, SmartTel, Total Endurance and WiperLock are trademarks of Microchip Technology Incorporated in the U.S.A. and other countries.

SQTP is a service mark of Microchip Technology Incorporated in the U.S.A.

All other trademarks mentioned herein are property of their respective companies.

© 2005, Microchip Technology Incorporated, Printed in the U.S.A., All Rights Reserved.

Printed on recycled paper.

# QUALITY MANAGEMENT SYSTEM CERTIFIED BY DNV == ISO/TS 16949:2002 ===

Microchip received ISO/TS-16949:2002 quality system certification for its worldwide headquarters, design and wafer fabrication facilities in Chandler and Tempe, Arizona and Mountain View, California in October 2003. The Company's quality system processes and procedures are for its PICmicro® 8-bit MCUs, KEEL00® code hopping devices, Serial EEPROMs, microperipherals, nonvolatile memory and analog products. In addition, Microchip's quality system for the design and manufacture of development systems is ISO 9001:2000 certified.



# WORLDWIDE SALES AND SERVICE

#### **AMERICAS**

**Corporate Office** 

2355 West Chandler Blvd. Chandler, AZ 85224-6199 Tel: 480-792-7200 Fax: 480-792-7277 Technical Support:

http://support.microchip.com

Web Address: www.microchip.com

Atlanta

Alpharetta, GA Tel: 770-640-0034 Fax: 770-640-0307

**Boston** 

Westborough, MA Tel: 774-760-0087 Fax: 774-760-0088

Chicago Itasca, IL

Tel: 630-285-0071 Fax: 630-285-0075

Dallas

Addison, TX Tel: 972-818-7423 Fax: 972-818-2924

**Detroit** 

Farmington Hills, MI Tel: 248-538-2250 Fax: 248-538-2260

Kokomo

Kokomo, IN Tel: 765-864-8360 Fax: 765-864-8387

Los Angeles

Mission Viejo, CA Tel: 949-462-9523 Fax: 949-462-9608

San Jose

Mountain View, CA Tel: 650-215-1444 Fax: 650-961-0286

Toronto

Mississauga, Ontario,

Canada

Tel: 905-673-0699 Fax: 905-673-6509 ASIA/PACIFIC

**Australia - Sydney** Tel: 61-2-9868-6733 Fax: 61-2-9868-6755

**China - Beijing** Tel: 86-10-8528-2100 Fax: 86-10-8528-2104

China - Chengdu
Tel: 86-28-8676-6200
Fax: 86-28-8676-6599

China - Fuzhou

Tel: 86-591-8750-3506 Fax: 86-591-8750-3521

China - Hong Kong SAR

Tel: 852-2401-1200 Fax: 852-2401-3431

**China - Shanghai** Tel: 86-21-5407-5533

Fax: 86-21-5407-5066
China - Shenyang

Tel: 86-24-2334-2829 Fax: 86-24-2334-2393

China - Shenzhen

Tel: 86-755-8203-2660 Fax: 86-755-8203-1760

China - Shunde

Tel: 86-757-2839-5507 Fax: 86-757-2839-5571

**China - Qingdao** Tel: 86-532-502-7355 Fax: 86-532-502-7205 ASIA/PACIFIC

India - Bangalore Tel: 91-80-2229-0061 Fax: 91-80-2229-0062

India - New Delhi

Tel: 91-11-5160-8631 Fax: 91-11-5160-8632

**Japan - Kanagawa** Tel: 81-45-471- 6166 Fax: 81-45-471-6122

Korea - Seoul

Tel: 82-2-554-7200 Fax: 82-2-558-5932 or 82-2-558-5934

Singapore

Tel: 65-6334-8870 Fax: 65-6334-8850

Taiwan - Kaohsiung Tel: 886-7-536-4818

Fax: 886-7-536-4803 **Taiwan - Taipei** 

Tel: 886-2-2500-6610 Fax: 886-2-2508-0102

**Taiwan - Hsinchu** Tel: 886-3-572-9526 Fax: 886-3-572-6459 **EUROPE** 

Austria - Weis

Tel: 43-7242-2244-399 Fax: 43-7242-2244-393

Denmark - Ballerup Tel: 45-4450-2828

Fax: 45-4485-2829

France - Massy Tel: 33-1-69-53-63-20 Fax: 33-1-69-30-90-79

**Germany - Ismaning** Tel: 49-89-627-144-0

Tel: 49-89-627-144-0 Fax: 49-89-627-144-44

Italy - Milan

Tel: 39-0331-742611 Fax: 39-0331-466781

Netherlands - Drunen

Tel: 31-416-690399 Fax: 31-416-690340

England - Berkshire Tel: 44-118-921-5869 Fax: 44-118-921-5820

03/01/05